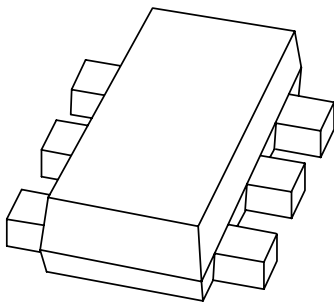


# DATA SHEET



## **PEMB13**

PNP resistor-equipped transistors;  
R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

Preliminary specification

2002 Jan 14

**PNP resistor-equipped transistors;  
R1 = 4.7 kΩ, R2 = 47 kΩ**

**PEMB13**

**FEATURES**

- 300 mW total power dissipation
- Very small 1.6 mm × 1.2 mm × 0.55 mm ultra thin package
- Improved thermal behaviour due to flat leads
- Self alignment during soldering due to straight leads
- Replaces two SC-75/SC-89 packaged transistors on same PCB area
- Reduces required PCB area
- Reduced pick and place costs.

**APPLICATIONS**

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

**DESCRIPTION**

PNP resistor-equipped transistors in a SOT666 plastic package.

**MARKING**

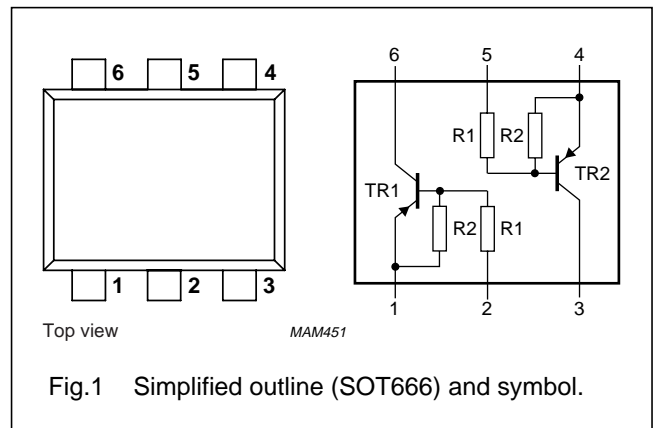
TYPE NUMBER	MARKING CODE
PEMB13	45

**QUICK REFERENCE DATA**

SYMBOL	PARAMETER	MAX.	UNIT
V <sub>CEO</sub>	collector-emitter voltage	-50	V
I <sub>CM</sub>	peak collector current	-100	mA
TR1	PNP	-	-
TR2	PNP	-	-
R1	bias resistor	4.7	kΩ
R2	bias resistor	47	kΩ

**PINNING**

PIN	DESCRIPTION
1, 4	emitter TR1; TR2
2, 5	base TR1; TR2
6, 3	collector TR1; TR2



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PEMB13

**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
<b>Per transistor unless otherwise specified</b>					
V <sub>CB0</sub>	collector-base voltage	open emitter	–	–50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	–	–50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	–	–10	V
V <sub>I</sub>	input voltage positive negative		–	+5	V
			–	–30	V
I <sub>O</sub>	output current (DC)		–	–100	mA
I <sub>CM</sub>	peak collector current		–	–100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	–	200	mW
T <sub>stg</sub>	storage temperature		–65	+150	°C
T <sub>j</sub>	junction temperature		–	150	°C
T <sub>amb</sub>	operating ambient temperature		–65	+150	°C
<b>Per device</b>					
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	–	300	mW

**Note**

1. Transistor mounted on a FR4 printed-circuit board.

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	notes 1 and 2	416	K/W

**Notes**

1. Transistor mounted on an FR4 printed-circuit board.
2. The only recommended soldering method is reflow soldering.

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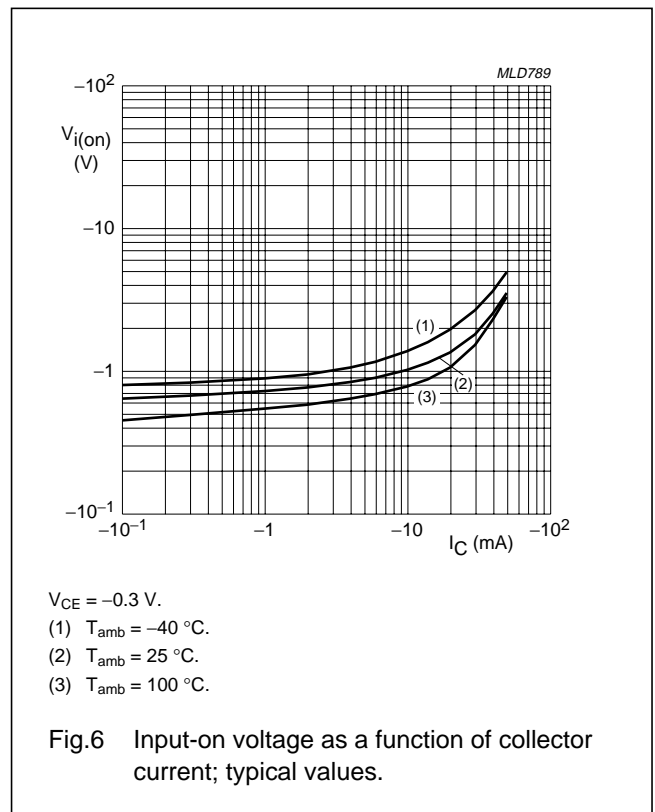
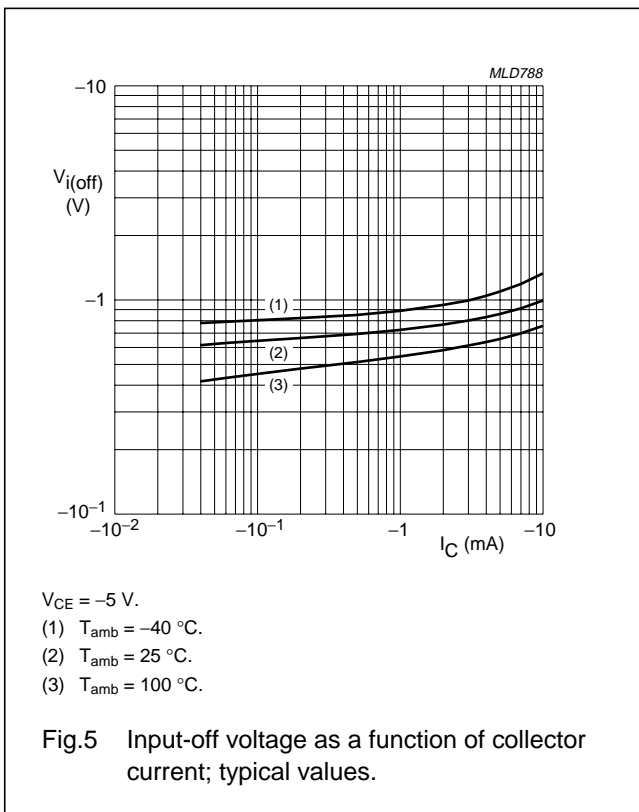
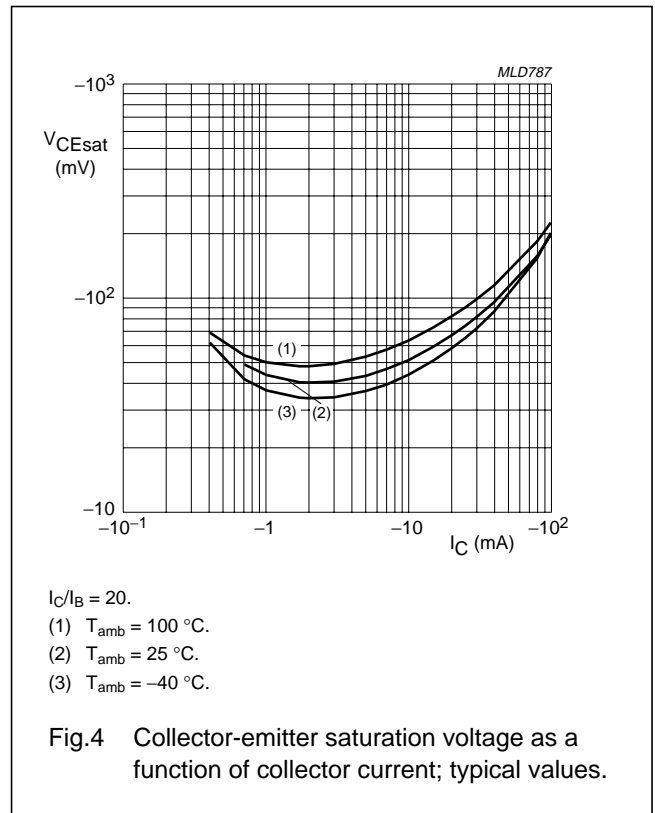
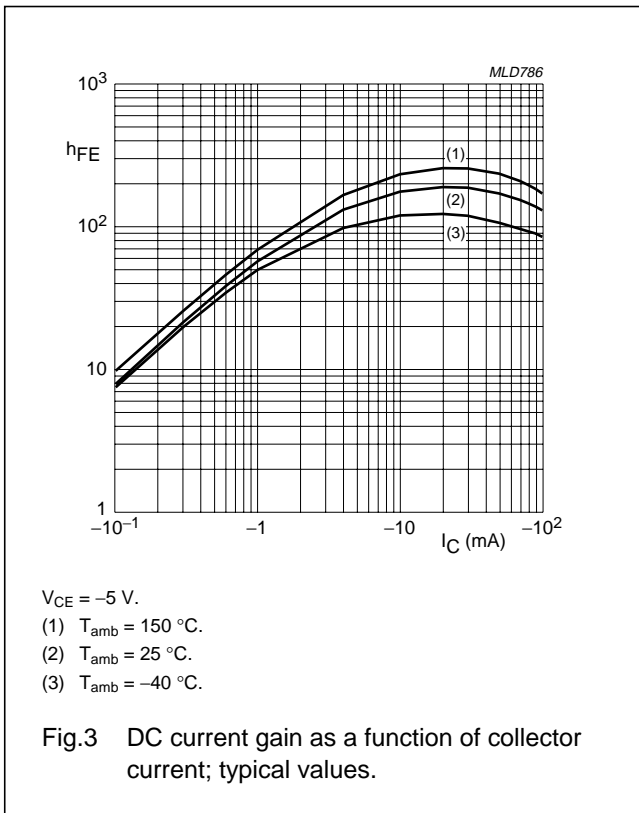
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**CHARACTERISTICS** $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
<b>Per transistor unless otherwise specified</b>						
$I_{\text{CBO}}$	collector-base cut-off current	$V_{\text{CB}} = -50 \text{ V}$ ; $I_{\text{C}} = 0$	–	–	–100	nA
$I_{\text{CEO}}$	collector-emitter cut-off current	$V_{\text{CE}} = -50 \text{ V}$ ; $I_{\text{B}} = 0$	–	–	–1	$\mu\text{A}$
		$V_{\text{CE}} = -30 \text{ V}$ ; $I_{\text{B}} = 0$ ; $T_{\text{j}} = 150 \text{ }^\circ\text{C}$	–	–	–50	$\mu\text{A}$
$I_{\text{EBO}}$	emitter-base cut-off current	$V_{\text{EB}} = -5 \text{ V}$ ; $I_{\text{C}} = 0$	–	–	–170	$\mu\text{A}$
$h_{\text{FE}}$	DC current gain	$V_{\text{CE}} = -5 \text{ V}$ ; $I_{\text{C}} = -10 \text{ mA}$	100	–	–	
$V_{\text{CEsat}}$	collector-emitter saturation voltage	$I_{\text{C}} = -5 \text{ mA}$ ; $I_{\text{B}} = -0.25 \text{ mA}$	–	–	–100	mV
$V_{\text{i(off)}}$	input off voltage	$V_{\text{CE}} = -5 \text{ V}$ ; $I_{\text{C}} = -100 \mu\text{A}$	–	–0.6	–0.5	V
$V_{\text{i(on)}}$	input on voltage	$V_{\text{CE}} = -0.3 \text{ V}$ ; $I_{\text{C}} = -5 \text{ mA}$	–1.3	–0.9	–	V
R1	input resistor		3.3	4.7	6.1	$\text{k}\Omega$
$\frac{R2}{R1}$	resistor ratio		8	10	12	
$C_{\text{c}}$	collector capacitance	$I_{\text{E}} = I_{\text{e}} = 0$ ; $V_{\text{CB}} = -10 \text{ V}$ ; $f = 1 \text{ MHz}$	–	–	3	pF

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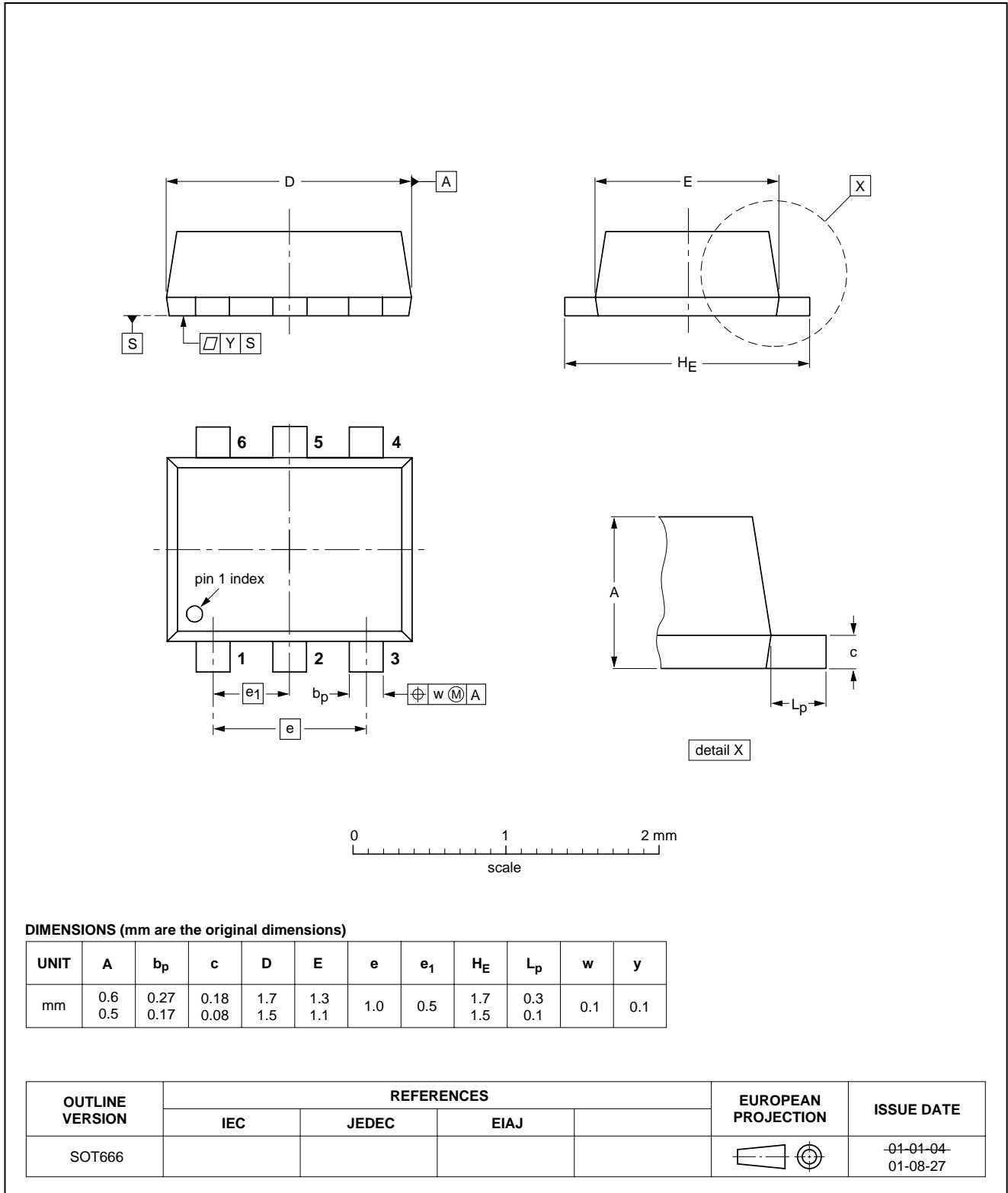
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PEMB13

PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT666



PNP resistor-equipped transistors;  
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PEMB13

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DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
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